OIF	E 30.15	IN THE UNITED STATES PATER	TAND TRADEMARK OFFICE	#14
	·	application of ya TANINO et al.)) Art Unit: 1765	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
	Appln	. No.: 09/771,556) Ex: R.M. Kunemund	12000
	Filed:	January 30, 2001)	9
	For:	SINGLE CRYSTAL SIC AND A METHOD OF GROWING THE SAME)))	

REPLY

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

The following remarks are offered in reply to the Office Action of December 16, 2002 and as an enclosure to the RCE being filed concurrently herewith.

REMARKS

Claims 1-10 were further examined and rejected as follows: (1) claims 1-6, 9 and 10 as unpatentable under 35 USC 103(a) over Tanino et al '279; and (2) claims 7 and 8 as unpatentable under 35 USC 103(a) also over Tanino et al '279.

While the rejections are separately stated, they are identical in that they both involve only Tanino et al '279.

In the previous Response it was noted that the invention claimed here and that disclosed in the Tanino et al '279 patent both have an α -SiC substrate and a polycrystalline β -SiC plate. It was noted, however, that the similarity stops there. According to the present invention,